NSN 5961-00-132-4854

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View Online at https://aerobasegroup.com/nsn/5961-00-132-4854 **Inclosure Material:** Metal **Overall Length:** 1.525 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 120.0 collector to emitter voltage, dc with specified circuit between base and emitter **Current Rating Per Characteristic:** 25.00 amperes source cutoff current and 25.00 amperes source cutoff current blank and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig:

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